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# Identification of damage and fracture modes in power electronic packaging from experimental micro-shear tests and finite element modeling

S. Msolli <sup>a</sup>, A. Baazaoui <sup>b</sup>, J. Alexis <sup>b</sup>, H.S. Kim <sup>a,\*</sup>

<sup>a</sup> Department of Mechanical, Robotics and Energy Engineering, Dongguk University-Seoul, 30 Pildong-ro 1-gil, Jung-gu, Seoul 100-715, Republic of Korea

<sup>b</sup> Université de Toulouse, INP/ENIT, LGP, 47, Avenue d'Azereix, F-65013 Tarbes, France

#### ABSTRACT

Micro-shear tests are performed in order to characterize the mechanical behavior and the fracture of the chip/metallized ceramic substrate assemblies of power electronic devices. These assemblies are elaborated using three types of junctions: AuGe solder/Au or Ag finish, transient liquid phase bonding (TLPB) AgIn/Ag finish and Ag nanoparticles/Au or Ag finish. The experiments are associated to finite element simulations of both nano-indentation and micro-shear tests. The mechanical behavior of the different assembly interfaces is represented using an in-built cohesive zone model (CZM) available in the user friendly finite element code Abaqus<sup>®</sup>. It is worth noting that the fracture mechanisms observed during the test and service periods of the power electronic packaging are not only due to the debonding at the interfaces but also to the initiation and growth of voids in the joint. Therefore, in addition to the CZM model, Gurson-Tvergaard-Needlmann (GTN) damage model is used in combination with the Rice bifurcation theory to correctly describe the fracture in the joint and, therefore the overall fracture mechanism of the entire junction. The simulation results are compared with the experimental force displacement curves and the SEM observations in order to assess the implemented model.

Keywords: Micro-shear CZM model GTN model Bifurcation theory Finite element method (FEM)

#### 1. Introduction

One of the challenges in high temperature power electronics is the reliability of the chip/substrate in the packaging assembly. This concerns not only the quality of the die attachment but also the thermomechanical stability of the thin or thick metallizations plated either on the chip or on the copper double bonded ceramic substrate (DBC) surfaces. Experimental studies on power electronics assemblies presented in previous frameworks have shown cohesive and interfacial ruptures within the junctions (solder, Ag nanoparticles, ...), the Cu substrate and the diamond chip [1-3]. At high loading rates, the damage originates close to the interfaces due to the formation of fragile intermetallic compounds, the presence of defects at the interfaces or the weak adhesion of certain layers of surface finishing metallization [4,5]. However, fracture mainly remains in the bulk solder at slow strain rates. In order to optimize the design of high-temperature packaging, in particular with regard to their lifetime, it is no longer sufficient to know the mechanical behavior of the constitutive materials. Indeed, interfaces and junctions are privileged zones of initiation and propagation

\* Corresponding author.

E-mail address: Heungsoo@dongguk.edu (H.S. Kim).

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Notations
Mathematical operators and symbols
          x derivative with respect to time
(\chi_{ij})
          second order tensor x (i and j)
x: x = x_{ij} x_{ij} contracted product of two second order tensors x_{ii}
x \otimes x = x_{ii} x_{kl} tensorial product of two second order tensors x_{ii}
Variables and parameters
          elastic stiffness tensor (MPa)
\boldsymbol{D}, \boldsymbol{D}^p
          macroscopic strain and plastic strain rate tensors
           Young modulus (MPa), Poisson ratio
E, v
f, f_0, f_c, f_F total, initial, critical, final volume fraction of voids
f_N, s_N, \varepsilon_N nucleation material parameters
          fracture energy of the cohesive element (MPa.mm)
K
          hardening coefficient (MPa)
K_h
          cohesive element stiffness (MPa.mm<sup>-1</sup>)
          power exponent
n
          normal to the Gurson yield surface (tensor)
n
'n
          vector normal to the localization band
q_1, q_2, q_3
          Gurson model parameters
t_i, t_i^0
          dual stress vector of the cohesive element, maximum value of stress (MPa)
          relative displacement of the cohesive element in direction i (mm)
          relative displacement at damage initiation and complete failure (mm)
          maximum relative displacement reached during loading (mm)
\delta_{ij}
          second order unit tensor
          vield strain of the matrix
          effective stress (MPa) and plastic strain of the matrix
          macroscopic stress tensor (MPa)
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of cracks in packaging; it is, therefore, important to be able to describe this overall mechanism using finite element modeling tools. The interfaces are mainly represented by cohesive laws which make it possible to evaluate the initiation and the evolution of the interfacial damage by linking the effort at the interface to its opening distance. However, the parameters of these laws are not exploitable from standard characterization tests and specific tests must then be implemented. The behavior laws of cohesive elements are usually described in terms of traction versus separation, which relates the interface relative displacement to the traction vector. Generally, the cohesive elements behave elastically until damage initiation and obey a softening behavior afterwards. The specific energy dissipated by the cohesive element can be calculated from the area under the curve. Different constitutive laws of the cohesive zone model have been proposed in the literature [6–11]. Since the shape of the function may influence the results of the simulation [12,13], it is crucial to identify a law that is suitable for capturing the interfacial fracture extension behavior of the cohesive layers. According to the nature of the material (ductile, brittle, etc.) and the type of loading considered (monotonic or cyclic loadings), the cohesive zone model can be defined. The bilinear cohesive zone model is currently the most widely used model for interfacial fracture behavior simulation due to its ability to describe different fracture modes and its availability in ABAQUS® software. Thus, it has been widely used to characterize the interfacial damage behavior in power electronic packaging [14,15]. These studies showed the performance of the bilinear cohesive zone methods for describing and predicting crack initiation and propagation at the interfaces of electronic assemblies. They also demonstrated the convergence between the numerical simulation and experimental results.

Damage can also be observed in the solder joints. Damage is mainly present in the form of micro-voids. These voids grow and nucleate during the service period leading to cracking and failure. To describe this phenomenon and for lifetime prediction, many studies have focused on continuum damage theories or fatigue criteria to describe degradation in solders. These models are mainly coupled to plasticity or viscoplasticity constitutive equations to describe the plastic deformation prior to damage initiation [16,17]. For example, some fatigue criteria such as Darveaux [18] or Manson-Coffin [19] are usually used because they are practical in numerical frameworks and give correct predictions. They can predict the lifetime of real products with complex geometry. However, the models take into account only the initial and final states of the material. The practical procedure to identify material behavior using these fatigue models is usually geometry dependent. In the general framework of continuum thermodynamics of irreversible processes, micro mechanical and phenomenological damage models are widely used [20,21]. These models are built from complex constitutive equations that require advanced integration methods. Another approach for describing fracture in solders is the maximum entropy fracture model. This type of

model permits life predictions for a structure in the presence of microstructural uncertainty using the maximum entropy principle [22]. Among the interesting features in the model, a single damage parameter is used for the crack initiation and propagation in solder joints. Some interesting frameworks have used cohesive zone fracture mechanics and the Disturbed State Concept to predict the crack trajectory and fatigue life of solder interconnections subjected to both isothermal temperature cycling and anisothermal temperature cycling conditions [23]. The method correlates very well with the experimentally observed damage. A number of other studies dealt with the evolution of the damage within the void volume fraction [24–26]. They consider damage as an internal variable which particularly depends on the stress triaxiality. Voids effects are also taken into account using the specific yield function proposed by Gurson [27] or Tvergaard-Needlman [28] which introduces the volume fraction of voids in the dissipation or viscoplastic potentials [29]. A major framework consists on describing voids nucleation and growth of creeping solids using a particular formulation of the Cocks creep law. The model is successfully applied for the case of cyclic shear of tin based solders [16,17].

The main aim of the current paper is to conciliate the interfaces and joint damage in a finite element modeling. We introduce the development of a tool to describe the damage behavior of both interfaces and joints of power electronics assemblies based on experimental observations. The applications are concerned with the elaboration of electronic components by *AuGe* soldering, transient liquid phase bonding of *Ag-In*, or the sintering of *Ag* nanoparticles. This tool is based on the combination of simple shear tests coupled with an inverse method of parametric identification.

In this contribution, we first describe the experimental procedure and the results from the shear and nano-indentation experiments. These experiments will serve as verification and validation of the finite element framework. In the second section, a finite element modeling of the performed nano-indentation and shear tests is carried out. A bilinear cohesive zone model (CZM) and GTN damage model are selected for the interfaces failure and for the description of damage behavior of the joint, respectively. Since strain localization occurs prior to the initiation of cracks in the joint, the Rice bifurcation theory is adopted. The most interesting features of this approach are its physically based character and its ability to detect the occurrence of necking instabilities under complex loading conditions. Accordingly, we selected this approach for use in the prediction of the moment of strain localization in electronic junctions. The coupled bifurcation theory and GTN model are implemented in the finite element code Abaqus/explicit® as user subroutine VUMAT. The models are calibrated and validated using the previously obtained experimental results.

#### 2. Experimental characterization

#### 2.1. Elaboration of the shear assemblies

Shear assemblies are manufactured using different techniques. These assemblies are constituted of Ni/Au or Ag metallized Oxygen/Halogen Free Copper (OHFC) inserts of dimensions 3 mm  $\times$  3 mm  $\times$  2 mm which are bonded on Ni/Au or Ag metallized OHFC copper substrates of dimensions 30 mm  $\times$  20 mm  $\times$  2 mm using different joining techniques: AuGe soldering with both Ni/Au and Ag metallization on the substrates, transient liquid phase bonding (TLPB) using Ag-In with both In preform and In metallization and, sintering of Ag nanoparticles (melting temperature  $T_m$  = 961 °C) with both Au and Ag finish metallization on the substrates. The thickness of Ni and Au metallization is 4  $\mu$ m and 3  $\mu$ m respectively. The thicknesses of the Ag metallization used to elaborate the AuGe, Ag-In and Ag nanoparticles junctions are 50  $\mu$ m, 4  $\mu$ m and 4  $\mu$ m, respectively. Table 1 summarizes the metallization and thickness for each type of assembly. The gold germanium solder is a 88Au12Ge eutectic alloy with a melting temperature of 356 °C. The TLPB technique is based on the diffusion of In into Ag metallization after reflow and annealing of In. The expected Ag-In junction is a solid phase eutectic of which the melting temperature is up to 695 °C. This eutectic is composed of 33 wt% of In. The overall thickness of the junctions (including metallizations) is about 100  $\mu$ m. A cross-section of the assemblies is presented to study the chemical composition of the junctions.

Microstructural observations using SEM and physico-chemical analyses of junctions formed by AuGe soldering on an Au finish or an Ag finish were carried out on the metallographic cross-sections. For the AuGe junction on an Au finish, these analyses show the formation of a continuous joint, free from defects. No noticeable porosity is observed either at the interfaces or in the joint, as demonstrated in Fig. 1(a). The microstructure of the joint differs depending on whether it is located near the

**Table 1**Metallization thickness of the inserts and substrates used to elaborate the shear assemblies

	Metallizat		
Joint	Ni	Au	Ag
AuGe	4	3	50
Ag nanoparticles	-	3	4
Ag-In	-	_	4

For the bond formed by AuGe soldering on an Ag finish, the joints formed are continuous and of high quality, as illustrated in Fig. 2(a). The morphology of these joints is homogeneous, symmetrical and presents no defects. The Energy-dispersive X-ray spectroscopy (EDX) analysis in Fig. 2(b) shows the presence of a gold-rich phase at the two interfaces of the AuGe/Cu insert and AuGe/Cu substrate. In the center of the bond, a regular eutectic structure is observed with the presence of two phases: a Au-rich phase and a Ge-rich phase. The evaluation of the chemical composition and the micrographic analysis show the presence of a 5  $\mu$ m thick interdiffusion zone between the Ag metallization and the AuGe solder at both AuGe/Cu interfaces. This new AuGeAg ternary alloy which constitutes an interphase between the Ag layer and AuGe has a melting temperature of 500 °C, higher than that of AuGe which is in the order of 360 °C [30]. In the case of this junction, no intermetallic layer is observed at the interfaces.

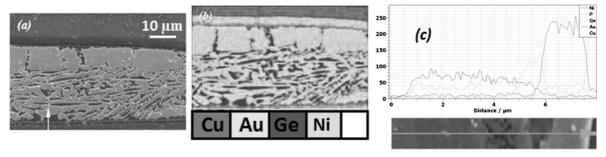
Fig. 3(a) shows the microstructural analyses carried out from metallographic cross-sections of the Ag-In junction obtained with indium metallization. The micrographs show the formation of a continuous joint with the presence of a few porosities in the center of the bond. The presence of the porosities in the joint is the result of the reflow operation; the porosities can be induced in particular by the initially rough structure of the indium. Thus, the evaluation of the chemical composition from an EDX profile reveals that the joint is composed of a maximum of about 20 wt% of indium at the center of the bond (Fig. 3(c)).

Microstructural analyses of the Ag-In bond carried out with In preform show the formation of a more porous bond than that produced with In metallization (Fig. 3(b)). These porosities are caused by the rough and porous structure of the In solder before reflow. The EDX analysis of the cross-section profile is almost the same as that observed previously for the Ag-In junction made with In deposited metallization. The maximum In composition of the junction is about 20 wt% at the center of the junction. This composition tends to decrease toward the interfaces with the insert or substrate (Fig. 3(d)).

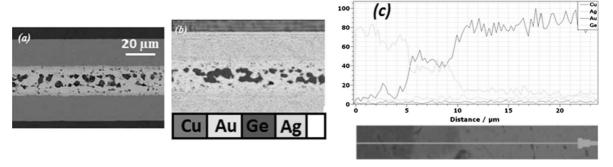
Physicochemical observations were made and analyses were carried out of the bond formed by sintering of the Ag nanoparticles. As illustrated in Fig. 4(a), the micrographic analysis shows the formation of a continuous, homogeneous, and uniform joint without macroscopic defects. In the microstructure of the junction, a high porosity ratio is observed among the Ag grains which are smaller than 10  $\mu$ m in size. EDX mapping shows the presence of carbon compounds spread over the entire joint (Fig. 4(b)).

# 2.2. Shear experiments

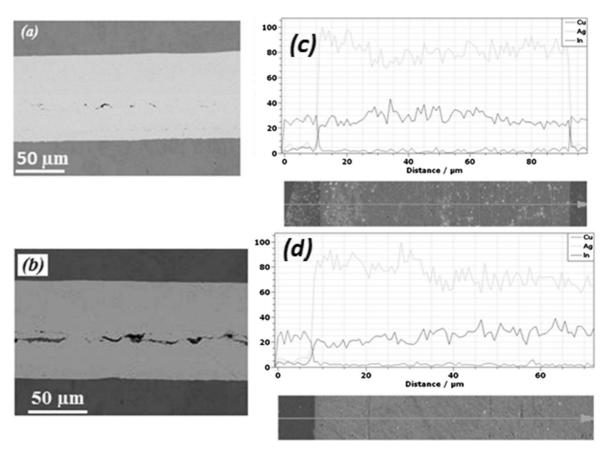
Displacement rate-controlled shear tests with a constant velocity of 1 mm/min are carried out at room temperature on elaborated shear test assemblies. The loading corresponds to an estimated strain rate of 0.16/s. The implementation of these experiments is performed in order to highlight the predominant shear behavior observed during the elaboration process and thermal cycling. Therefore, it is expected that these experiments activate the same physical phenomena. The choice of the experiment and the measured quantities are very important and the obtained results must be carefully monitored. The experiments are carried out using an INSTRON tensile machine dedicated to performing shear tests on electronic devices.



**Fig. 1.** (a) Micrograph of the cross-section of the *AuGe/Au* junction. (b) EDX mapping of the junction showing thicknesses and elements present. (c) Chemical composition of the junction against thickness.



**Fig. 2.** (a) Micrograph of the cross-section of the *AuGe/Ag* junction. (b) EDX mapping of the junction showing thicknesses and elements present. (c) Chemical composition of the junction against thickness.



**Fig. 3.** Micrograph of the cross-section of the Ag-In junction performed with (a) In metallization and (b) In preform. Chemical composition of the junction against thickness. (c) In metallization and (d) In preform.

The load cell of the tensile machine can handle forces up to 2 kN. The samples are fixed on the machine tray, while the punch that must push the insert is driven at a constant displacement. Meanwhile, an innovative non-contact detecting system using the digital images correlation technique (DIC) was introduced to measure the displacement of the assembly. This technique is an optical method of non-contact measurement of two-dimensional (2D) kinematic fields. The image correlation measurement system consists of a Charge Coupled Device (CCD) and an optical system. The system is able to measure the surface displacements of an object with a displacement resolution of 5  $\mu$ m. A schematic diagram of the experimental device is shown in Fig. 5. The method of fine shear displacement measurement involves tracking markers between the sheared stud and a substrate reference element. The non-contact measuring system makes it possible to record the displacement between the two markers A and B located on the upper flat surface of the sheared part and the upper flat surface of a

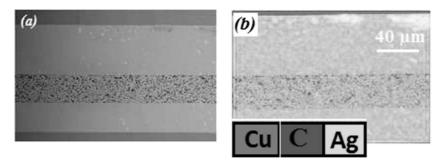


Fig. 4. (a) Micrograph of the cross-section of the Ag nanoparticles junction. (b) EDX mapping of the junction showing thicknesses and present elements.

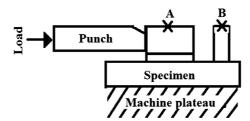


Fig. 5. Schematic representation of the principle of the performed shear test.

reference stud, respectively. It should be noted that the dark color reference markers in Fig. 5 represent points A and B to measure the displacement of the assembly.

The reference pad is placed so that points A and B are in the focal plane of the sensor. Therefore, the measurement is insensitive to the parasitic displacement induced by the various elements of the machine and the measurement corresponds to the real shear displacement of the evaluated stud. The results will therefore be used to extract the load-displacement responses of the assembly and to calibrate the parameters of the interfaces and the junction models.

Fig. 6 shows the force displacement curves recorded by the INSTRON tensile machine. In Fig. 6(a), the results of displacement obtained from the force-displacement curves for the different cases of assemblies correspond to the accumulation of displacements specific to the joints, the interfaces, and the displacement induced by the mounting rigidity. Since the mounting system is extremely stiff compared to the remaining constitutive materials of the tested assembly, the force displacement responses are quasi-linear. The effect of the mounting rigidity is also deduced by stackable responses at the earliest stage of loading. Nevertheless, it can observed that the assemblies elaborated with the *AuGe* solder and *Ag* metallization are clearly the strongest. The junctions based on silver nanoparticles are not resistant compared to the other studied junctions. This is due to the nature of this type of junction, which is extremely porous at the gross state and after the thermomechanical process. The initial void density in these junctions is very high leading to weakening of the obtained bond. A fast drop of the reaction force is observed for all types of junctions. This indicates that immediately before this brittle failure, the crack propagates least on the assembly interfaces. Fig. 6(b) shows the force displacement curves with the experimental shear displacements measured using the DIC technique for the two types of junctions i.e. *AuGe/Au* and nano *Ag/Ag*. Actually, the

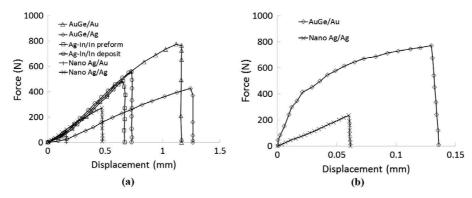


Fig. 6. Force displacement curves of shear tests (V = 1 mm/min and  $T = 25 \,^{\circ}\text{C}$ ) for Cu-Cu assemblies. (a) Machine tray displacement. (b) Real shear displacement.

nonlinear behavior of the force displacement response can be observed, demonstrating that plasticity occurred in this assembly before cracking. This observation is based on the fact that copper and *AuGe* alloy exhibit plastic deformation before fracture. However, this is different for the *Ag* nanoparticles/*Ag* junction where the overall response is linear. Since *Ag* is a highly ductile material, the cracking is interpreted as an early debonding of the brittle and weak assembly interfaces.

The shear tests are followed by the fractographic analysis of the various junctions. This analysis makes it possible to locate the fracture areas and thus to analyze the damage modes in order to identify the fracture path. The micrograph (Fig. 7(a)) and the EDX analysis of the fracture faces of AuGe specimens on Au finish reveals two distinct zones of different sizes: a Ni-rich area and smaller Au and Ge-rich areas (Fig. 7(b)). These analyses show that the failure first occurred in the AuGe/deposited Ni interface at the Cu substrate side, then propagated in the joint to reach the AuGe/deposited Ni interface at the Cu insert side. Therefore, one can deduce that the rupture is mixed: mainly adhesive at the interfaces between the Ni deposit and the AuGe solder, but also cohesive in the AuGe solder (Fig. 7(c)). In the case of the AuGe junctions on the Ag finish, the micrographic analysis (Fig. 8(a)) and the chemical composition show a substantially cohesive failure in the joint, close to the Cu insert. Indeed, according to Fig. 8(b), the EDX analysis shows high proportions of Au and Ge. However, Ag-rich areas are also present on the fracture faces of this junction. The rupture of the AuGe junction is therefore mixed: cohesive in the solder and adhesive at the AuGe/Ag deposit interface of the Cu insert (Fig. 8(c)). No trace of Cu is present on the faces of the two types of junctions. Analysis of the fracture faces of the Ag-In TLPB specimens showed a cohesive fracture in the joint in the case of assemblies with *In* metallization (Fig. 9(a)) and a mixed rupture in the case of assemblies with *In* preform (Fig. 11(a)). The fracture is cohesive in the AuGe solder and adhesive in the Ag-In/Ag deposit interface at the insert side. Evaluations of the chemical composition and the EDX analysis performed on the fracture faces reveal the exclusive presence of Ag and In after rupture in both types of assembly (Figs. 9(b) and 11(b)). The evaluation of the fracture faces of the Ag-In assembly with In metallization using 3D optical profilometer showed that rupture occurred at 62 µm with respect to the surface of the Cu substrate while the total joint has an initial thickness of about 100 µm before loading (Fig. 10).

The EDX analyses of the fracture faces of the Ag nanoparticle sintering specimens show the exclusive presence of Ag (Fig. 12(b)). The micrograph analysis (Fig. 12(a)) and evaluation of the chemical compositions of the Ag nanoparticle assemblies illustrate a mixed mode of failure. The rupture is cohesive in the Ag nanoparticles joint and adhesive at the Ag nanoparticles/Ag deposit interface of the Cu insert (Fig. 12(c)). From these various tests, it is concluded that the mechanical strength of the AuGe assembly is better on the Ag deposit. This can be explained in two ways: the solder forms an interphase composed of an Au-Ag solid solution at the AuGe/Ag deposit interface. This is possible because the two constituents Au and Ag, are perfectly miscible. Nevertheless, a seemingly fragile AuNiGe compound is formed at the interface between the solder and the Ni deposit because the thin Au deposit dissolves during the reflow of AuGe. The better mechanical strength of the Ag-In junction with the deposited In compared to that with the In preform can be explained by the better metallurgical quality of the Ag-In junction performed by deposition which is void-free. Finally, the junction with the Ag nanoparticles has a limited mechanical strength considering the porous structure of the bond. It should be noted that the shear strength of 28 MPa that was obtained with the Ag deposit corresponds to the maximum mechanical strength of 30 MPa recommended by the supplier (NBETech).

# 2.3. Nano-indentation experiments

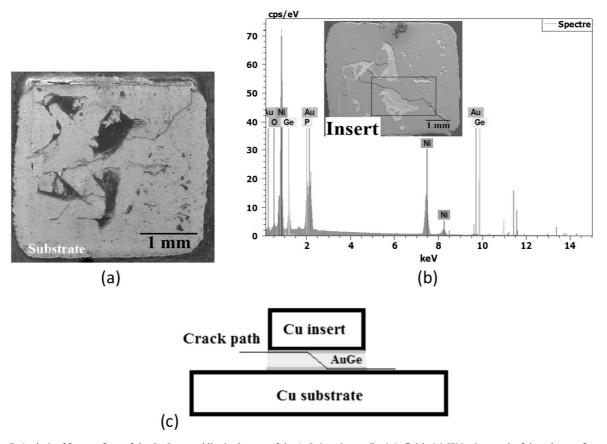
Additional nano-indentation tests were performed at room temperature on the cross-section of the shear assemblies. Specifically, 15 idents were made in the AuGe and Ag nanoparticles layers. The tip used for the test is a Berkovich indenter with a Dynamic Contact Module (DCM) to determine the force displacement response of the joint materials. The nano-indentation test includes a unique loading unloading cycle with a maximum imposed displacement of the tip of 1  $\mu$ m. The loading unloading curves are illustrated in Fig. 13. Different behaviors are recorded for the two tested materials. The AuGe alloy exhibits more hardening than the Ag nanoparticles as the load reached is 3 times higher than that of Ag.

#### 3. Finite element modeling

The performed nano-indentation and the shear tests are simulated using the finite element code Abaqus/Explicit. The experimental data such as force displacement responses are employed to calibrate the material parameters of the CZM and GTN models. More specifically, the nano-indentation tests are retained as reference results to determine the parameters of the Swift law. Subsequently, the damage parameters including those of the GTN and CZM models are obtained using shear tests with a fixed insert dimension of 3 mm  $\times$  3 mm. Finally, in order to evaluate the robustness of the entire set of model parameters, a finite element simulation of a validation shear test is performed using a different geometry configuration for the assembly.

# 3.1. Nano-indentation test

Finite element simulation of a 2-D axisymmetric nano-indentation model was performed as illustrated in Fig. 14. The model consists of a rigid conical indenter that moves toward an elastoplastic substrate. A loading and unloading cycle is applied in this model. The indenter reaches a maximal displacement of 1 µm and is then retrieved. The substrate was meshed

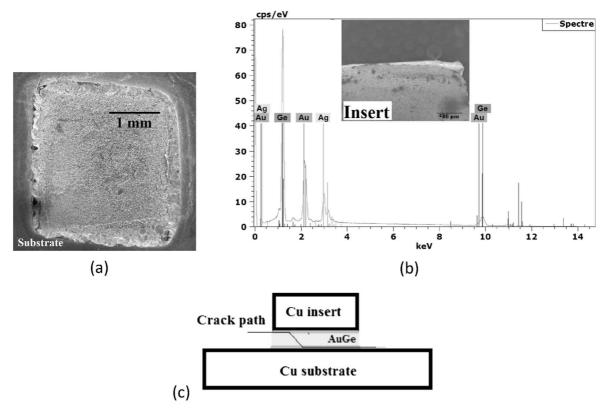


**Fig. 7.** Analysis of fracture faces of the *Cu-Cu* assemblies in the case of the *AuGe* junction on (b, c) *Au* finish. (a) SEM micrograph of the substrate fracture faces. (b) EDX chemical composition of the insert fracture faces. (c) Schematic of the crack path in the shear assembly.

with 6874 four-node bilinear axisymmetric quadrilateral, reduced integration elements as shown in Fig. 14. For more precision in stress distribution, a fine mesh was used under the contact area and in the vicinity of the tip. However, the mesh is coarser everywhere else to reduce the computational time. The simulations are performed using Abaqus/explicit solver with a nonlinear geometry option. As noted previously, the substrate shows an elastoplastic behavior that obeys the Swift law. No damage is considered in these simulations. The substrate has an "infinite" thickness (100  $\mu$ m) compared to the imposed tip displacement.

#### 3.2. Shear test

A simplified finite elements simulation of the tested assembly is performed under the FE code Abagus. The aim of these computations is to simulate the crack initiation and propagation in the assembly. The fractography results for both the AuGe solder and the Ag nanoparticles based assemblies discussed in Section 1, showed a brittle damage in the Cu/solder interfaces. To predict the interfacial and brittle damage behavior observed experimentally, the irreversible and bilinear cohesive zone model [14,15] can be applied. The 2D configuration of the assembly or the elementary packaging shown in Fig. 15 is composed of an OHFC copper insert and an OHFC copper substrate that are bonded together with the different junctions described previously, as well as two cohesive layers and a rigid shear tool. The two cohesive zone layers are placed in the junction/insert and junction/substrate interfaces, where fracture is typically observed. The whole part is subjected to shear within a displacement controlled loading. The imposed tool velocity is 0.2 mm/s for a total time of 1 s. These conditions lead to a maximal insert displacement of 0.2 mm since fracture is initiated at a maximum of 0.15 mm displacement. Thus, the simulations are quasi-static. For the copper insert and substrate, an elastoplastic model with isotropic hardening is adopted [31]. For the behavior of the junctions, Swift plastic law is retained. Indeed, most of the commonly used solders exhibit viscoplastic behavior since the temperature of the power electronic assembly is high compared to the melting temperature of the solder. This is the case for many alloys such as tin, lead or leadfree solders that have a melting temperature close to the application temperature. In the present case, the choice of elastoplastic modeling of the junctions is motivated by the fact that the targeted new packaging assemblies were initially designed and tested for temperatures up to 125 °C. This temperature represents about one-third of the melting temperature of the AuGe solder alloy (T<sub>m</sub>: 365 °C). This temperature is also



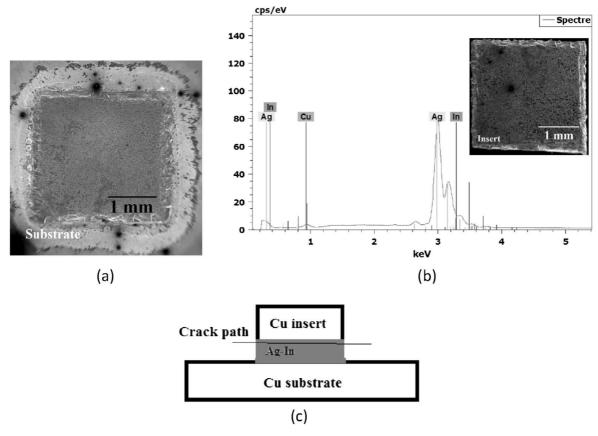
**Fig. 8.** Analysis of fracture faces of the *Cu-Cu* assemblies in the case of the *AuGe* junction on *Ag* finish. (a) SEM micrograph of the substrate fracture faces. (b) EDX chemical composition of the insert fracture faces. (c) Schematic of the crack path in the shear assembly.

very low compared to the melting temperature of silver nanoparticles ( $T_m$ : 800 °C). In the case of extreme temperature, the model needs to be extended to the case of viscoplasticity. A complete description of the viscoplastic modeling of the tin solder behavior using unified Chaboche constitutive equations and using the Chaboche-type model combined with the Cocks's damage law for porous creep can be found in [16,17], respectively. The models have previously been implemented in the FE code Abaqus. The Chaboche-type model is especially interesting as it can capture commonly observed features such as kinematic hardening as well as voids nucleation and growth in the solders under cyclic shear. It proposes a modified viscoplastic potential based on the Cocks creep law which can be a convenient alternative to incorporating damage in the modeling framework.

Since the main mechanism of initiation and propagation of cracks in the junction is due to the nucleation and growth of voids, this law is then coupled to the GTN damage model to describe degradation in the solder. To determine the moment of strain localization in the junction, a bifurcation approach is used based on the calculation of the preferred orientation of the sliding plane. The thickness of the cohesive and joint layers, measured experimentally, is about 4 and 5  $\mu$ m, respectively. The two cohesive layers were modeled using a 4-nodes bilinear quadrilateral element of type 2D cohesive (COH2D4). The length of the cohesive elements was 100  $\mu$ m. In the thickness, the cohesive zone must be discretized with a single layer of cohesive elements [8]. In this case, the path of the cracking is naturally determined by the overall field and the cohesive response. The junction, the insert and the substrate layers were meshed with a 4-node bilinear 2D plane strain quadrilateral elements (CPE4R). The size of the elements in the solder is the same as that of the cohesive elements.

## 3.3. CZM model

For pure-mode I and pure-mode II or mode III loading, the available traction separation law (TSL) assumes the linear elastic behavior followed by the initiation and evolution of damage. A high initial stiffness is used to hold together the top and bottom faces of the debonding element in the linear elastic range. Once the peak values of the normal or shear nominal stress have been reached, the stiffnesses are gradually reduced to zero. The analytical expression of the bilinear cohesive model law relating the traction or the dual stress vector t to the interface's relative displacement vector  $\delta$  is expressed as follows [12,32]:



**Fig. 9.** Analysis of the fracture faces of the *Cu-Cu* assemblies performed using *Ag-In* TLPB with *In* metallization. (a) SEM micrograph of the substrate fracture faces. (b) EDX chemical composition of the insert fracture faces. (c) Schematic of the crack path in the shear assembly.

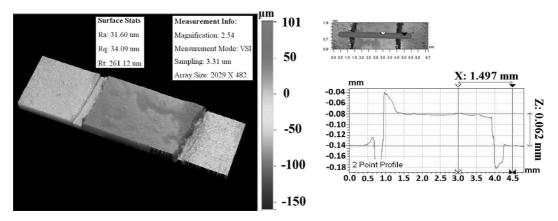
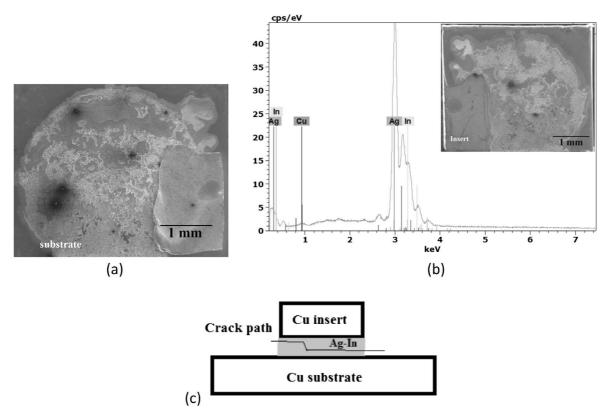


Fig. 10. Scanned profile of the fracture faces (substrate side) obtained from 3D optical profilometry.

$$t_{i} = \begin{cases} K_{h}\delta_{i} & \text{if } \delta_{i} \leq \delta_{i}^{0} \\ (1 - D_{i})K_{h}\delta_{i} & \text{if } \delta_{i}^{0} < \delta_{i} < \delta_{i}^{f} & i = 1,3 \\ 0 & \text{if } \delta_{i} \geqslant \delta_{i}^{f} \end{cases}$$

$$(1)$$

$$D_{i} = \frac{\delta_{i}^{f} \left( \delta_{i}^{\max} - \delta_{i}^{0} \right)}{\delta_{i}^{\max} \left( \delta_{i}^{f} - \delta_{i}^{0} \right)} \tag{2}$$



**Fig. 11.** Analysis of the fracture faces of the *Cu-Cu* assemblies performed using *Ag-In* TLPB with *In* preform. (a) SEM micrograph of the substrate fracture faces. (b) EDX chemical composition of the insert fracture faces. (c) Schematic of the crack path in the shear assembly.

where  $\delta_i^0$  and  $\delta_i^f$  represent the relative displacement at damage initiation and complete failure, respectively.  $\delta_i^{\max}$  refers to the maximum value of the relative displacement attained during the loading history.  $K_h$  is the cohesive element stiffness.  $\delta_i^0$  and  $\delta_i^f$  are given by Alfano [12]:

$$\delta_i^0 = \frac{t_i^0}{K_h} \quad \text{and} \quad \delta_i^f = \frac{2G^c}{t_i^0} \tag{3}$$

 $G^c$  represents the fracture energy of the cohesive elements. A fundamental aspect in the formulation of the cohesive model is the requirement that the energy dissipated at a fracture propagation must be equal to the fracture energy, so that the following relation (Eq. (3)) must be satisfied:

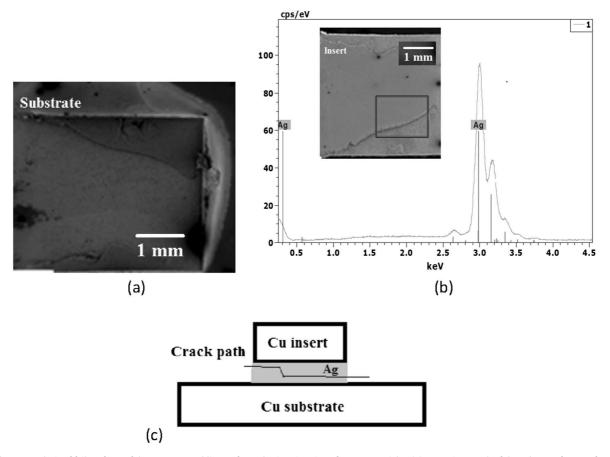
$$G_i = \int_0^{\delta_i^f} t_i d\delta_i = G^c \tag{4}$$

In this paper, only the pure-mode II debonding problem is considered, so that the analysis is simplified by focusing on scalar interface relationships relating one relative-displacement component  $\delta$  to t. In this case, the CZM characteristic parameters are the cohesive element stiffness  $K_h$  which is related to the cohesive layer modulus  $E^c$ , the fracture energy  $G^c$  and the strength  $t^0$ . Fig. 16 illustrates the different variables of the CZM model in the case of a pure-mode II debonding problem.

# 3.4. GTN model

The original version of the Gurson model [27] was extended by Tvergaard and Needleman [28] and the latter version is referred to as the Gurson, Tvergaard, and Needleman (GTN) model. The GTN model considers ductile failure as a repercussion of nucleation and growth as well as the coalescence of spherical voids. The expression of the yield function is given as follows:

$$\Phi_{\text{GTN}} = \left(\frac{q}{\bar{\sigma}}\right)^2 + 2q_1 f^* \cosh\left(\frac{3q_2 \Sigma_m}{2\bar{\sigma}}\right) - 1 - q_3 f^{*2} = 0, \tag{5}$$



**Fig. 12.** Analysis of failure faces of the *Cu-Cu* assemblies performed using sintering of *Ag* nanoparticles. (a) SEM micrograph of the substrate fracture faces. (b) EDX chemical composition of the insert fracture faces. (c) Schematic of the crack path in the shear assembly.

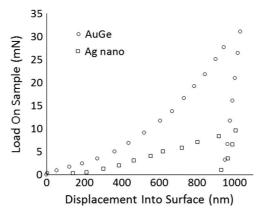


Fig. 13. Loading unloading curves for AuGe and Ag Nanoparticles joints.

 $\Sigma$  is the macroscopic stress vector. The effective stress q and the pressure stress  $\Sigma_m$  are equal to  $\sqrt{3\Sigma : \Sigma/2}$  and  $\mathrm{tr}(\Sigma)/3$ , respectively,  $\bar{\sigma}$  is the flow stress of the fully dense matrix, and  $f^*$  is the modified volume fraction of voids.  $q_1$ ,  $q_2$  and  $q_3$  are material constants and take the values of 1.5, 1 and 2.25, respectively [33].

 $f^*$  is introduced in order to improve the description of the coalescence stage. Its expression is given by the empirical formula introduced by Tvergaard and Needleman [28]:

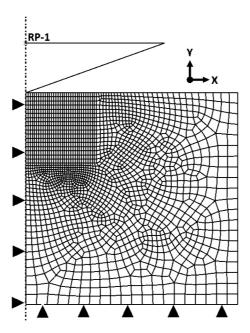


Fig. 14. Schematic representation of the tip and the sample used in the finite element model.

$$f^* = f_c + \delta_{GTN}(f - f_c) \quad \text{where} \quad \delta_{GTN} = \begin{cases} 1 & \text{if } f \leqslant f_c \\ \frac{f_u - f_c}{f_F - f_c} & \text{if } f_c < f < f_F. \\ f_u & \text{if } f_F \leqslant f \end{cases}$$
 (6)

In the previous equation,  $f_F$  represents the final volume fraction prior to failure,  $f_c$  is the critical volume fraction of voids, and  $f_u$  is mainly expressed as a function of the parameters  $q_1$ ,  $q_2$  and  $q_3$ :

$$f_u = \left(q_1 + \sqrt{q_1^2 - q_3}\right) / q_3. \tag{7}$$

For the evolution of the void volume fraction, the porosity rate  $\dot{f}$  is additively decomposed into the nucleation [34] and growth contributions, denoted as  $\dot{f}_n$  and  $\dot{f}_g$ , respectively:

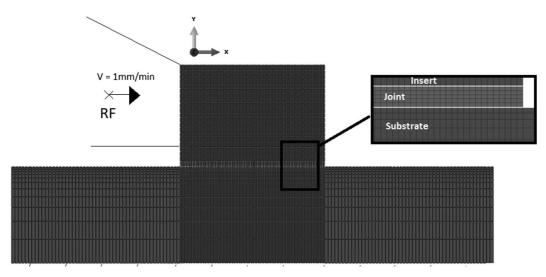


Fig. 15. 2D finite element configuration of the shear specimen. Cohesive elements (COH2D4) are adopted for the modeling of debonding in the junction interfaces.

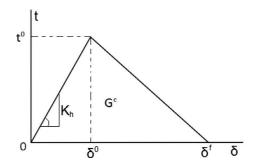


Fig. 16. Schematic of a traction separation curve for cohesive elements showing the main variables of the CZM model.

$$\dot{f}_n = A_n \dot{\bar{\varepsilon}}^p = \frac{f_N}{s_N \sqrt{2\pi}} \exp\left[-\frac{1}{2} \left(\frac{\bar{c}^p - \varepsilon_N}{s_N}\right)^2\right] \dot{\bar{\varepsilon}}^p,\tag{8}$$

and

$$\dot{f}_g = (1 - f)tr(\mathbf{D}^p), \tag{9}$$

where  $\mathbf{D}^p$  is related to  $\Phi_{GTN}$  by the normality rule:

$$\mathbf{D}^p = \dot{\gamma} \frac{\partial \Phi_{GIN}}{\partial \Sigma}. \tag{10}$$

 $\dot{\gamma}$  denotes the plastic multiplier.  $f_N$  represents the volume fraction of inclusions that are likely to nucleate,  $\varepsilon_N$  refers to the equivalent plastic strain for which half of the inclusions have nucleated, and  $s_N$  is the standard deviation on  $\varepsilon_N$ .

The expression of the flow stress  $\bar{\sigma}$  of the fully dense matrix is defined by the Swift law:

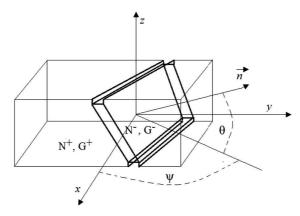
$$\bar{\sigma} = K(\varepsilon_0 + \bar{\varepsilon}^p)^n. \tag{11}$$

The equivalence between the rates of macroscopic and microscopic (matrix) plastic work is deduced from the following equation:

$$(1-f)\bar{\sigma}\dot{\bar{\varepsilon}}^p = \Sigma : \mathbf{D}^p. \tag{12}$$

## 3.4.1. Bifurcation approach

The Rice bifurcation theory [35] is used to predict the onset of plastic strain localization in the sheet metals studied. In this approach, bifurcation should be interpreted as the occurrence of a nonhomogeneous strain mode, in the form of an infinite localization band defined by its normal  $\vec{n}'$ , within a continuous medium that is subjected to a homogeneous strain state (Fig. 17). Making use of the equilibrium and compatibility conditions, it is possible to derive the following localization criterion, namely the singularity of the acoustic tensor, which only involves the normal  $\vec{n}'$  to the localization band and the analytical tangent modulus  $\vec{L}$ :



**Fig. 17.** Infinite localization band in the metal sheet at the moment of strain localization and the associated angles that defines the normal in the (X, Y) and (X, Z) plane.

$$\det(\vec{n}'.L.\vec{n}') = 0. \tag{13}$$

The normal  $\vec{n}'$  can be defined geometrically in the (X, Y) and (X, Z) planes by the angles  $\theta$  and  $\psi$  (Fig. 17). In order to compute the determinant of Eq. (13) for every time increment, the normal  $\vec{n}'$  is swept in the half range of the coordinates system at intervals of 1°. This obviously implies that  $\theta \in [0, \pi)$  and  $\psi \in [0, \pi/2)$  due to the plane symmetry are considered for the sheet (finite element). As noted previously, the strain localization is reached when Eq. (13) reaches a global negative minimum which implies that the normal  $\vec{n}'$  takes a particular orientation defined by the two angles  $(\theta_{\min}, \psi_{\min})$ .

The analytical tangent modulus L is related to the elastic-plastic tangent modulus  $C^{ep}$  by:

$$L = C^{ep} + C_1 - C_2 - C_3, \tag{14}$$

where  $C_1$ ,  $C_2$  and  $C_3$  are fourth-order tensors that can be expressed, after some mathematical derivations, as:

$$\mathbf{C}_{1ijkl} = \Sigma_{ij} \, \delta_{kl}; \quad \mathbf{C}_{2ijkl} = \frac{1}{2} (\Sigma_{jl} \, \delta_{ik} + \Sigma_{jk} \, \delta_{il}); \quad \mathbf{C}_{3ijkl} = \frac{1}{2} (\Sigma_{ik} \, \delta_{jl} - \Sigma_{il} \, \delta_{jk}). \tag{15}$$

Note that if the fourth order elasto-plastic tensor  $\mathbf{C}^{ep}$  is symmetric, the analytical tangent modulus  $\mathbf{L}$  is not symmetric because of the contribution of the convective terms in Eq. (14). The elastic-plastic tangent modulus  $\mathbf{C}^{ep}$  is determined by expressing the improved GTN yield function and the plastic multiplier in the Kuhn-Tucker form as follows:

$$\Phi_{GIN} \leqslant 0; \quad \dot{\gamma} \geqslant 0; \quad \Phi_{GIN} \dot{\gamma} = 0.$$
 (16)

This form is convenient because it reveals that there is no plastic flow (i.e.,  $\dot{\gamma}=0$ ) when  $\Phi_{GTN}<0$ , while a strict plastic loading (i.e.,  $\dot{\gamma}>0$ ) necessarily implies that  $\Phi_{GTN}=0$  and  $\dot{\Phi}_{GTN}=0$ . The latter represents the consistency condition, and can be developed as follows:

$$\dot{\Phi}_{GTN} = \mathbf{V}_{\Sigma} : \dot{\Sigma} + V_{\bar{\sigma}} \dot{\bar{\sigma}} + V_{f^*} \dot{f}^* = 0. \tag{17}$$

The derivatives  $V_{\Sigma}, V_{\bar{\sigma}}$  and  $V_{f^*}$  are obtained analytically in the following forms:

$$\begin{cases} \mathbf{V}_{\Sigma} = \frac{2}{\bar{\sigma}} \left( \frac{\Sigma}{\bar{\sigma}} + \frac{q_1 q_2 f^*}{2\bar{\sigma}} \sinh \left( \frac{3 q_2 \Sigma_m}{2\bar{\sigma}} \right) \mathbf{I} \right), \\ V_{\bar{\sigma}} = -\frac{2}{\bar{\sigma}} \left( \left( \frac{q}{\bar{\sigma}} \right)^2 + 3 \frac{q_1 q_2 f^* \Sigma_m}{2\bar{\sigma}} \sinh \left( \frac{3 q_2 \Sigma_m}{2\bar{\sigma}} \right) \right), \\ V_{f^*} = 2 \left( q_1 \cosh \left( \frac{3 q_2 \Sigma_m}{2\bar{\sigma}} \right) - q_3 f^* \right). \end{cases}$$

$$(18)$$

The rate form of the hypo-elastic law allows us to express the stress rate in terms of the plastic multiplier  $\dot{\gamma}$ :

$$\dot{\Sigma} = \mathbf{C}^e : (\mathbf{D} - \dot{\gamma} \mathbf{V}_{\Sigma}) = \mathbf{C}^{ep} : \mathbf{D}. \tag{19}$$

**D** is the macroscopic strain rate tensor. After some mathematical derivations involving the normality rule (10) and Eqs. (13) and (14), the elastic-plastic tangent modulus is obtained as follows:

$$\mathbf{C}^{ep} = \mathbf{C}^{e} - \frac{(\mathbf{C}^{e} : \mathbf{V}_{\Sigma}) \otimes (\mathbf{V}_{\Sigma} : \mathbf{C}^{e})}{H_{\gamma}}, \tag{20}$$

where  $H_{\gamma}$  is defined by the following relation:

$$H_{\gamma} = \boldsymbol{V}_{\Sigma} : \boldsymbol{C}^{e} : \boldsymbol{V}_{\Sigma} - \frac{V_{\bar{\sigma}} \frac{\partial \bar{\sigma}}{\partial \bar{\sigma}^{p}}}{(1 - f)} \frac{\Sigma : \boldsymbol{V}_{\Sigma}}{\bar{\sigma}} - V_{f^{*}} \delta_{GTN} \left( \frac{A_{n}}{(1 - f)} \frac{\Sigma : \boldsymbol{V}_{\Sigma}}{\bar{\sigma}} + (1 - f) \boldsymbol{V}_{\Sigma} : \boldsymbol{I} \right). \tag{21}$$

### 3.4.2. Numerical implementation of the model

The numerical algorithm for the integration of the GTN model is described in this section. The GTN model will be discretized into incremental equations. We selected an implicit integration scheme for the GTN model since it is unconditionally stable, so convergence could be obtained for large time increments and therefore, a gain in the computation time could be achieved. The system of nonlinear equations is solved by the Newton-Raphson iterative method according to Ben Bettaieb et al. [36] at the Gauss point level. The procedure involves two steps: elastic predictor and plastic corrector. The total strain is decomposed into elastic and plastic parts:

$$\boldsymbol{\varepsilon} = \boldsymbol{\varepsilon}^e + \boldsymbol{\varepsilon}^p$$
 (22)

The total plastic strain increment is also separated into two parts:

$$\Delta \boldsymbol{\varepsilon}^{p} = \frac{1}{3} \Delta \varepsilon_{p} \boldsymbol{I} + \Delta \varepsilon_{q} \boldsymbol{n} \tag{23}$$

with

$$\Delta \varepsilon_p = \Delta \gamma \frac{\partial \Phi_{GIN}}{\partial \Sigma_m} \tag{24}$$

$$\Delta \varepsilon_q = \Delta \gamma \frac{\partial \Phi_{\text{GTN}}}{\partial q} \tag{25}$$

 $n = \frac{35}{20}$  is the flow direction for the isotropic material. Combining Eqs. (19) and (20) leads to the equality:

$$\Delta \varepsilon_q \frac{\partial \Phi_{GTN}}{\partial \Sigma_m} + \Delta \varepsilon_p \frac{\partial \Phi_{GTN}}{\partial q} = 0 \tag{26}$$

From the equivalence of the plastic work, one can deduce:

$$\Delta \bar{\varepsilon}^p = \frac{\sum_m \Delta \varepsilon_p + q \Delta \varepsilon_q}{(1 - f)\bar{\sigma}}.$$
 (27)

Finally, from the expression of the rate of the void volume fraction, it can be written that

$$\Delta f = \frac{f_N}{s_N \sqrt{2\pi}} \exp\left[-\frac{1}{2} \left(\frac{\bar{\varepsilon}^p - \varepsilon_N}{s_N}\right)^2\right] \Delta \bar{\varepsilon}^p + (1 - f) \Delta \varepsilon_p \tag{28}$$

In the case of isotropic materials, the normal to the yield surface  $\mathbf{n}$  is collinear to the direction of the deviatoric stress vector  $\mathbf{S}$ . The system of Eqs. (6), (26)–(28) need to be solved numerically by using the Newton-Raphson iteration scheme. Accordingly, a trial elastic stress is first calculated by assuming that strain increment is purely elastic in the current time step. If  $\Phi_{GTN} \leq \mathbf{0}$ , only the trail elastic stress is updated and one can proceed to the next time step. Otherwise, if  $\Phi_{GTN} > \mathbf{0}$ , the Newton-Raphson scheme is used to solve the set of equations described above. Four scalar variables  $(\Delta \varepsilon_p, \Delta \varepsilon_q, \Delta f, \Delta \overline{\varepsilon}^p)$  need to be determined at the end of each time step. Further details on the integration procedure and the determination of the consistent tangent modulus can be found in [36], where representative benchmarks are fully patented. The relevant algorithm was implemented into the finite element code ABAQUS/Explicit as a user subroutine VUMAT. The state variable controlling the element deletion for the crack propagation is the cubic square of the localization criterion  $\sqrt[3]{\det(\vec{n'}\cdot L.\vec{n'})}$ . The element is deleted when this variable becomes less than or equal to zero.

#### 3.4.3. Validation of the integration algorithm

An essential step involves assessing the implemented integration algorithm of the GTN equations. Therefore, the GTN model is used to describe the deformation of one CPE4R finite element. The element is represented as a cube with an edge dimension of 1 mm and is subjected to uniaxial tension. The loading and boundary conditions imposed on the cube are presented in Fig. 18.

The material parameters for the Al5754 aluminum material identified in [33] are used in this simulation. In the latter framework, the Swift hardening law has been adopted for the matrix material [33]. The material parameters of the Swift model were fitted on the basis of the experimental stress–strain curve [37]. The material parameters of the GTN model are given in Table 2:

Fig. 19 compares the numerical uniaxial response using the Abaqus GTN model and the response using the present GTN model integrated using the previously presented implicit algorithm (VUMAT). As shown in this figure, the responses obtained from implementation closely fit the Abaqus numerical curves. The onset of void coalescence is reached when the void volume fraction f becomes greater than the critical void volume fraction f as indicated in Fig. 19 (a) and (b). The material then softens and a stress drop is obtained as illustrated in Fig. 19(a).

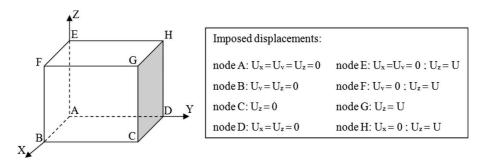
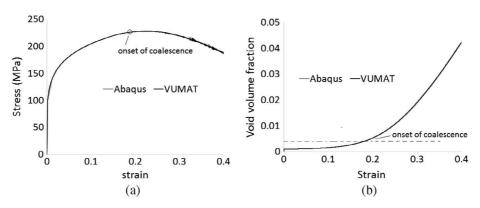


Fig. 18. Loading and boundary conditions applied to a single finite element.

**Table 2** Material parameters for the Al5754 aluminum material.

Junction	E (GPa)	ν	n	K (MPa)	$\varepsilon_0$	$f_0$	$f_c$	$q_1$	$q_2$	$q_3$	$s_N$	$\varepsilon_N$	$f_N$
Al5754	70	0.33	0.177	309.1	0.0017	$10^{-3}$	0.00284	1.5	1	2.15	0.1	0.32	0.034



**Fig. 19.** Comparison of the numerical responses for the uniaxial tension issued from the predefined GTN model (Abaqus) and the implemented GTN model (VUMAT). (a) Stress strain curve and (b) evolution of the void volume fraction.

#### 3.4.4. General procedure for parameters calibration

To evaluate the parameters of the CZM and GTN models, the nano-indentation and shear characterization tests of the assembly are related to their finite element models by using a parametric identification algorithm. The algorithm is based on the resolution of the inverse problem using a parametric calibration of the finite element model. First, the adopted method involves performing finite element simulations of the nano-indentation test in order to calibrate the parameters of the Swift law  $(n, K, \varepsilon_0)$ . Then, the optimized values of  $(n, K, \varepsilon_0)$  are fixed and used to simulate the shear tests in order to calibrate the damage parameters of the GTN and CZM models. For each identification step, the unknown model parameters vector  $\mathbf{x}$  is determined in order to ensure good agreement between the numerical response of the model and the experimental data. Thus, an error function is defined which corresponds to the difference between the numerical and experimental responses that will be minimized using one or more optimization methods. This identification procedure is summarized in Fig. 20. An initial model parameters set can be roughly determined provided that it gives the closest numerical response to the experimental data. The aim of this step is to minimize the computation time due to the numerous inverse problem iterations.

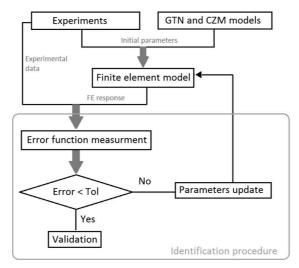


Fig. 20. Flowchart for the identification of model parameters using a parametric calibration procedure of the inverse problem.

**Table 3**Material parameters of GTN model and the cohesive zone model for the studied junctions.

Junction	E (GPa)	ν	n	K (MPa)	$\varepsilon_0$	$f_0$	$f_c$	$q_1$	$q_2$	$q_3$	$s_N$	$\varepsilon_N$	$f_N$	E <sup>c</sup> (GPa)	G <sup>c</sup>	t <sup>0</sup>
AuGe Au finish Ag nano Ag finish Cu	80 70 115	0.32 0.3 0.36	0.3 0.17 0.19	960 200 297	$2.\times10^{-3}$ $2.\times10^{-3}$ $3.7\times10^{-3}$	$10^{-3}$ $10^{-1}$	$1.147 \times 10^{-3} \\ 0.101$	1.5 1.5	1	2.25 2.25	0.1 0.1	0.27 0.27	0.11 0.35	20 1	0.01 0.01	230 30

The resolution of the inverse parametric identification problem is performed by the Levenberg-Marquardt algorithm. The measurement of the error between the measured experimental response and the corresponding simulated value using the finite element model is taken through the calculation of the error function  $\mathfrak{I}$  given by Eq. (29).

$$\mathfrak{I} = \sqrt{\sum_{i=1}^{N_p} \left(\frac{F_i^{Num}(\mathbf{x}) - F_i^{Exp}}{F_i^{Exp}}\right)^2}$$
 (29)

 $F^{Exp}$  represents the experimental measure of the reaction force and  $F^{Num}$  represents the force obtained by the FE model.  $N_p$  is the number of points for the shear test and  $\mathbf{x}$  is the vector of model parameters. After obtaining the best set of model parameters, a final verification procedure is performed to assess the accuracy of the parameters. Then, finite element simulations of the shear test are conducted using a different geometry of the assembly. The dimension of the insert and the joint are increased from 3 mm  $\times$  3 mm to 4.7 mm  $\times$  4.7 mm in the case of the AuGe based assembly. Conversely, the metallizations thickness is changed from 5  $\mu$ m to 50  $\mu$ m for the Ag nanoparticles assembly. The latter steps are essential as they enable validation of the accuracy of the selected parameters for simulations of assemblies under different geometries and loading conditions. Based on this method, the identified material parameters for the GTN damage model and for the hardening law providing a good fit to the experimental data for the different types of junction are summarized in Table 3.

# 4. Results and discussion

As abovementioned, the behavior of the system is quasi-static. A solver using an implicit numerical integration scheme is mainly used for the simulations. Nevertheless, the main limits could be the difficulty in converging this solver up to the total rupture of the rupture zone, especially when the fracture energy is small; in other words, brittle damage occurs in the interfaces. This results in a major disadvantage in the identification procedure since it is not possible to fully construct the force-displacement curve used to form the residual vector. In addition, element deletion cannot be recovered for the solid joint with the implicit solver, and crack propagation therefore cannot be observed. To solve this problem, we used a solver with an explicit numerical integration scheme (Abaqus/Explicit); these solvers have a considerable robustness within strong nonlinearities. The explicit solver permits the use of the element deletion technique, which enables the representation of the discontinuity by gradual element deletion from the mesh. The element status is linked to a state variable, of which the default value is 1. When the state variable was equal to 0, the associated element is deleted by prescribing a zero stress state within the element. However, using an explicit solver, excessive computational times and oscillating force due to stress wave propagation in the element may be exhibited. To overcome this obstacles, a time scaling factor of  $10^{-6}$  is adopted.

Fig. 21 shows the nano-indentation and shear force-displacement curves obtained for the two types of assemblies. Good agreement between the experimental data and numerical results are recorded. With the set of parameters presented, the explicit solver allow the complete construction of the curve. For the *Cu/Cu* assembly with the *AuGe* alloy, the experimental and numerical shear responses are close, provided that the crack is not initiated. Beyond an overall displacement of the order of 0.13 mm and a force of 770 N, the numerical curve drops with a combined interface/solder cracking. The rupture failure with the numerical model is slightly faster than that of the experimental system as the acceleration factor deduced from the critical void volume fraction is slightly overestimated.

For sintered silver nanoparticle joints, the numerical force displacement response closely matches the experiment result since the crack propagates rapidly in the brittle *Ag* metallization. Therefore, small plasticity is recorded for the silver nanoparticles joint that is concentrated in the nanoparticles layer borders. In this case, the straightforward rupture on the test is fairly well represented by the numerical model.

Fig. 22 illustrates the results of the Von Mises equivalent stress distributions at the final state (total failure) in the different layers of the assemblies studied. Naturally, interest is only focused on layers where damage is observed and/or crack have occurred. This means that only the cohesive elements layers and the joint are represented. Fig. 22(a) illustrates the final crack appearing in the Cu/Cu assembly performed with the AuGe solder. A very short time is recorded between the initiation and total failure of the junction. The crack initiation is produced at the left side of the junction in a small portion of the cohesive layer. It then propagates in the middle of the junction inside the solder layer until total failure. Other very small cohesive delaminations are dispersed along the junction width. This numerical result is in agreement with the experimental observations shown in Fig. 7 where traces of Au and solder are detected on the insert surface using EDX spectroscopy.

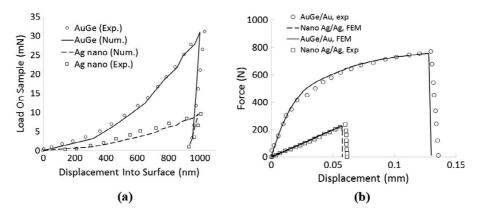
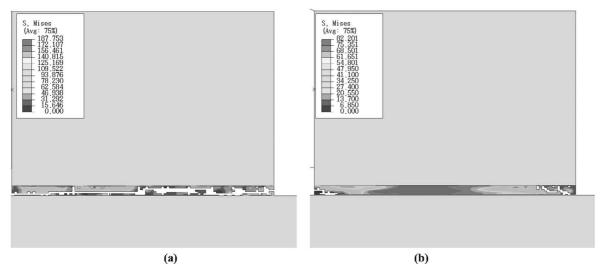


Fig. 21. Comparison between experimental data and calibrated force displacement responses. (a) Nano-indentation tests and (b) shear tests.



**Fig. 22.** Final crack configurations of the Cu/Cu assemblies and Von Mises stress distribution in the different junction layers. (a) AuGe/Au finish assembly and (b) Ag nanoparticles/Ag finish assembly.

The experimental result showed a mixed fracture of the solder layer and Au metallization. As shown in Fig. 22(b), a crack initiates first at the Ag nanoparticles layer in both the right and left sides of the joint and across the entire thickness. The crack then propagates rapidly in the bottom Ag interface until total failure of the assembly. Therefore, the major part of the crack is located on the Ag interface leaving a small amount of Ag nanoparticles on the top of the substrate. This observed phenomenon corroborates the obtained fracture faces of the Ag nanoparticles/Ag assemblies where the Ag nanoparticles are detected over almost the entire surface of the insert, while only leaving two small Ag areas near the insert borders.

Fig. 23 shows the distribution of the volume fraction of voids f in the AuGe and Ag nanoparticles joints. For the AuGe joint, a crack propagates from the left side to the right side of the junction. Elements deletion first acts in the left side of the solder joint along the interface neighbor. Then, the cracking path changes the direction to a privileged orientation (i.e. the middle of the junction), and finally deviates again towards the cohesive layer at the right side of the junction until total failure. For the Ag nanoparticles joint, a small crack occurs at the borders of the layer and evolves towards the bottom interface of the junction (Fig. 23(b)). The Ag nanoparticles layer has a high initial void volume fraction  $f_0$  (0.1) which is very close to the critical void volume fraction  $f_c$  (0.101). Therefore, the early cracking of the joint is due to the rapid increase of the void volume fraction from  $f_0$  to  $f_c$ . The volume fraction of voids is high at the borders and at the middle of the joint since a significant amount of plastic deformation is recorded early at these regions.

Fig. 24 corroborates the previously exposed comments and illustrates the evolution of damage or the void volume fraction f obtained by finite element simulations against the undeformed junction width. The figure shows that most of the damage occurs at the left side of the AuGe joint (Fig. 24(a)). The void volume fraction takes a value of  $9.5 \times 10^{-4}$  smaller than  $f_0$  ( $f_0 = 10^{-3}$ ) in the right side corner of the solder layer (distance of 3 mm along path). This is due to the compressive stress generated in this junction area. For the Ag nanoparticles layer, the fracture occurs on the borders of the junction. Fig. 24 (b) also shows that the highest void volume fractions are recorded in these areas. Since the initial void volume fraction is

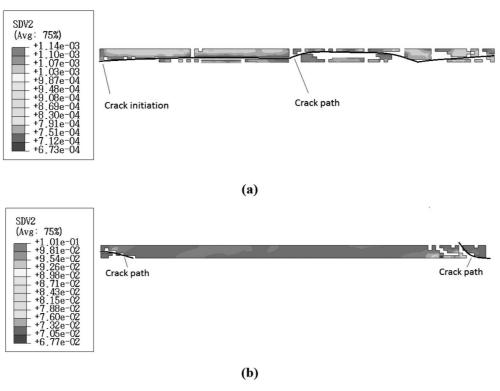
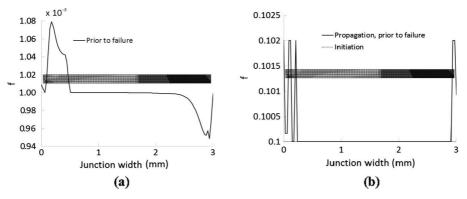


Fig. 23. Distribution of void volume fraction in the joint layer during initiation and propagation as well as at the total failure of the joint. (a) AuGe/Au based assembly. (b) Silver nanoparticles based assembly.



**Fig. 24.** Evolution of the void volume fraction f along a path crossing the joint layer during initiation and propagation as well as at the total failure of the joint. (a) AuGe/Au based assembly. (b) Ag nanoparticles based assembly.

close to the critical void volume fraction for both the AuGe and Ag nanoparticles junctions, the crack initiates and propagates rapidly, since the coalescence stage appears early.

Fig. 25 shows the evolution of the cubic square of the localization criterion against strain for the first failed element of the AuGe and Ag nanoparticles joints. The bifurcation theory needs to be used with a damage model (GTN in this case) in order to obtain softening (stress drop). The localization criterion is the principal indicator of the failure in the material. Indeed, this condition depends on the stress state which, in turn depends of the void volume fraction. In the first stage of loading, the criterion considerably decreases as the stress increases due to the elastic and plastic deformation. Subsequently, the criterion stabilizes rapidly when the stress reaches a steady state, indicating the approach of coalescence. At the moment of the strain localization (onset of coalescence), the material begins to soften, a drop of stress is generated and the localization criterion decreases again until zero value at total failure. At this time, the element is deactivated (fail). Therefore, the localization criterion  $\det(\vec{n}'.L.\vec{n}')$  is considered as the state variables controlling the element deletion.

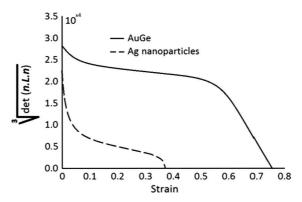


Fig. 25. Strain localization condition until total failure of the material, extracted in the first failed element in the joints.

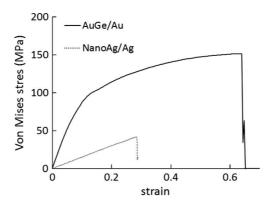
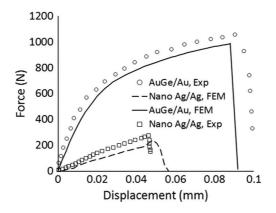


Fig. 26. Von Mises stress in the first element of the cohesive layer undergoing deletion. The figure shows both cases of AuGe/Au and Ag nanoparticles/Ag assemblies.

Fig. 26 shows the evolution of stress in the first cohesive element undergoing failure. Debonding begins when the stress reaches its maximum value and is completed when the stress reaches a zero value. The evolution of debonding from the initiation to the complete failure is very rapid as demonstrated by the vertical drop of the stress. The *Au* interfaces response (*AuGe* solder based assembly) is nonlinear as the fracture energy and the magnitude of the stress vector of the interface element are high. Subsequently, the *Ag* interface (*Ag* nanoparticles based assembly) is very brittle. It undergoes just a small straining before element failure since the magnitude of the stress vector in this case is considerably small.

Some concerns could arise about the accuracy of the identified model parameters and their ability to represent material behavior in a different geometry or configuration of the shear assembly. Therefore, additional shear tests are performed using the two types of junctions previously modeled using finite element simulations. In the present simulations, the same loading and boundary conditions are adopted. Nevertheless, for the *AuGe* based assembly, the dimension of the insert is



 $\textbf{Fig. 27.} \ \ \textbf{Force displacement curves is sued from validation shear tests.}$ 

increased from 3 mm  $\times$  3 mm to 4.7 mm  $\times$  4.7 mm. Consequently, the associated cohesive layers and joint follow the same change in dimensions. For the Ag nanoparticles based assembly, the thickness of the metallizations is modified. Henceforth, it takes the value of 50  $\mu$ m instead of 5  $\mu$ m. Moreover, copper is replaced by a purely elastic diamond as the insert material. This enables the present configuration to be closer to the real configuration. The numerical results and the experimental data are compared in terms of force displacement curves. Fig. 27 shows the force displacement curves of the relevant shear tests. The finite element modeling gives correct general trends but slightly underestimates the force level for the two types of assemblies. Higher forces are recorded for these assemblies as the geometric and material configuration changed. For the AuGe based assembly, the surface of contact between the different layers increased considerably leading to an increase of the reaction force. In the Ag nanoparticles assembly, replacing copper with diamond leads to a small increase of the experimental shear force from 230 N to 280 N. A small variation of the numerical force is observed which is due to a change in the crack direction. Progressive softening then occurs until total failure of the assembly.

#### 5. Conclusion

To study the crack initiation and propagation in power electronic assemblies, shear lap specimens are manufactured and subjected to micro-shear tests. The specimen consists of an Ni/Au or Ag metallized copper stud which is assembled into an Ni/Au or Ag metallized copper substrate using two types of joints: AuGe alloy joint and Ag nanoparticles joint. The experimental data obtained at room temperature showed that, for the AuGe based junction, the cracks propagate evenly along the surface of the joint and the interface, leading to a total break in the middle of the junction. The SEM and EDX fractography analyses show almost a mixed fracture: adhesive in the two Cu/solder interfaces and cohesive in the joint. However, the Ag nanoparticles based junction shows a failure mainly produced at the bottom Ag interface after a small initiation in the Ag nanoparticles joint. The SEM and EDX fractography analyses show a failure face advancing almost along the entire surface of the interface. For the two types of junction, the crack propagation is rapid either in the solder layer or in the Ag interface, as the latter is very brittle. Finally, regarding the obtained results from experiments, it seems that the soldering technique using AuGe alloy is the most convenient solution for power electronic components undergoing temperatures up to 125 °C. Moreover, the deposited Ag metallization performed on the copper stud and substrate is compatible with the solder components. Therefore, the junction formed with the AuGe solder layer and Ag metallization presents better mechanical behavior compared to the brittle junction formed with Ag nanoparticles and Ag metallization. The fragile aspect of the Ag nanoparticles junction is due to the poor quality of the interface between the Ag metallization and the Ag nanoparticles layer, even though the Ag nanoparticles layer presents good mechanical and thermal properties. To take further advantages of this Ag junction, the parameters of the sintering process may need to be better controlled in order to improve the solid diffusion of the Ag present in the substrates and the nanoparticles layer. Finite element modeling of the micro-shear tests is performed by using a bilinear CZM parameters for the Cu/AuGe and the Cu/Ag nanoparticles interfaces. A GTN damage model is coupled to the Rice bifurcation theory to describe damage initiation and propagation in the joints. The interfacial fracture of these assemblies was then simulated using 2D finite element modeling. The models parameters were identified using the inverse method involving the additional nano-indentation data, shear data and iterative finite element simulations. The obtained results show good agreement between the experimental data and the numerical responses. The coupled model demonstrated its ability to describe the mechanical behavior of the junctions until the strain localization. Finally, finite element simulations are needed to assess the behavior of the AuGe and Ag junctions during thermal cycling and to predict the lifetime of the obtained power electronics assemblies. Microstructural changes must be thoroughly studied in order to determine rupture mechanisms under cyclic thermal conditions. The parameters for the elaboration process have a direct influence on the thermomechanical behavior of the packaging. Therefore, an investigation of the effect of these control parameters is required mainly to overcome the causes of cracking in the elaborated electronic devices.

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